

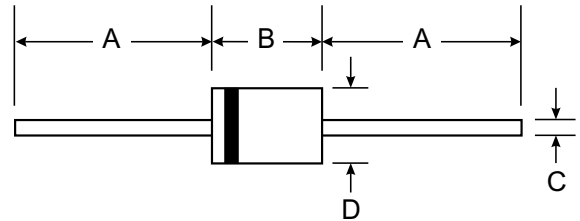
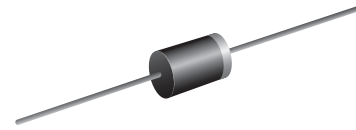
VOLTAGE RANGE: 100V
CURRENT: 2.0 A

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications

Mechanical Data

- Case : DO-15 Molded plastic
- Epoxy : UL94V-O rate flame retardant
- Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- Polarity : Color band denotes cathode end
- Mounting position : Any
- Weight : 0.465 gram



DO-15		
Dim	Min	Max
A	25.40	—
B	5.50	7.62
C	0.686	0.889
D	2.60	3.60
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SR2A0	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	100	Volts
Maximum RMS voltage	V_{RMS}	70	Volts
Maximum DC blocking voltage	V_{DC}	100	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length(see fig.1)	$I_{(AV)}$	2.0	Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	60.0	Amps
Maximum instantaneous forward voltage at 2.0A	V_F	0.85	Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	1.0 10.0	mA
Typical junction capacitance (NOTE 1)	C_J	80	pF
Typical thermal resistance (NOTE 2)	R_{qJA}	50.0	$^\circ\text{C}/\text{W}$
Operating junction temperature range	T_J	-65 to +150	$^\circ\text{C}$
Storage temperature range	T_{STG}	-65 to +150	$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

